# GaAs MMIC 6-BIT DIGITAL PHASE SHIFTER, 9-12.5 GHz 

## Typical Applications

The HMC642 is ideal for:

- EW Receivers
- Weather \& Military Radar
- Satellite Communications
- Beamforming Modules
- Phase Cancellation

Functional Diagram


Electrical Specifications, $T_{A}=+25^{\circ} \mathrm{C}$,
Vee $=-5 \mathrm{~V}$, Vdd= $=+5 \mathrm{~V}$, Control Voltage $=0 /+5 \mathrm{~V}$, 50 Ohm System

| Parameter | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: |
| Frequency Range | 9 |  | 12.5 | GHz |
| Insertion Loss* |  | 6.5 | 8.5 | dB |
| Input Return Loss* |  | 13 |  | dB |
| Output Return Loss* |  | 12 |  | dB |
| Phase Error* |  | $\pm 5$ | +15/-8 | deg |
| RMS Phase Error |  | 2.5 |  | deg |
| Insertion Loss Variation* |  | $\pm 0.25$ |  | dB |
| Input Power for 1 dB Compression |  | 28 |  | dBm |
| Input Third Order Intercept |  | 41 |  | dBm |
| Control Voltage Current |  | <250 |  | $\mu \mathrm{A}$ |
| Bias Control Current |  | <12 |  | mA |

*Note: Major States Shown

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## Insertion Loss, Major States Only



Input Return Loss, Major States Only


Output Return Loss, Major States Only


Normalized Loss, Major States Only


Relative Phase Shift Major States, Including All Bits


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Relative Phase Shift, RMS, Average, Max, All States


Input IP2, Major States Only


RMS Phase Error vs. Temperature


Input IP3, Major States Only


Input P1dB, Major States Only


Insertion Loss vs. Temperature, Major States Only


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Phase Error vs. State


Truth Table

| Control Voltage Input |  |  |  |  |  | Phase Shift (Degrees) <br> RFIN - RFOUT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Bit 1 | Bit 2 | Bit 3 | Bit 4 | Bit 5 | Bit 6 |  |
| 0 | 0 | 0 | 0 | 0 | 0 | Reference* |
| 1 | 0 | 0 | 0 | 0 | 0 | 5.625 |
| 0 | 1 | 0 | 0 | 0 | 0 | 11.25 |
| 0 | 0 | 1 | 0 | 0 | 0 | 22.5 |
| 0 | 0 | 0 | 1 | 0 | 0 | 45.0 |
| 0 | 0 | 0 | 0 | 1 | 0 | 90.0 |
| 0 | 0 | 0 | 0 | 0 | 1 | 180.0 |
| 1 | 1 | 1 | 1 | 1 | 1 | 354.375 |

Any combination of the above states will provide a phase shift approximately equal to the sum of the bits selected.
*Reference corresponds to monotonic setting

## Absolute Maximum Ratings

| Input Power (RFIN) | $30 \mathrm{dBm}\left(\mathrm{T}=+85^{\circ} \mathrm{C}\right)$ |
| :--- | :--- |
| Bias Voltage Range (Vdd) | -0.2 to +12 V |
| Bias Voltage Range (Vss) | +0.2 to -12 V |
| Channel Temperature (Tc) | $150^{\circ} \mathrm{C}$ |
| Thermal Resistance <br> (channel to die bottom) | $60^{\circ} \mathrm{C} / \mathrm{W}$ |
| Storage Temperature | -65 to $+150^{\circ} \mathrm{C}$ |
| Operating Temperature | -55 to $+85^{\circ} \mathrm{C}$ |

ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

Bias Voltage \& Current

| Vdd | Idd |
| :---: | :---: |
| 5.0 | 5.6 mA |
| Vss | Iss |
| -5.0 | 5.6 mA |

## Control Voltage

| State | Bias Condition |
| :---: | :---: |
| Low (0) | 0 to 0.2 Vdc |
| High (1) | Vdd $\pm 0.2 \mathrm{Vdc} @ 35 \mu \mathrm{~A}$ Typ. |

## Pad Descriptions

| Pad Number | Function | Description | Interface Schematic |
| :---: | :---: | :---: | :---: |
| 1, 3, 12, 14 | GND | These pads and die bottom must be connected to RF/DC ground. | $\begin{aligned} & \text { OGND } \\ & \overline{=} \end{aligned}$ |
| 2 | RFIN | This port is DC coupled and matched to 50 Ohms. | RFIN O- |
| 4 | Vdd | Voltage supply. |  |
| $\begin{aligned} & 5-7, \\ & 9-11 \end{aligned}$ | BIT1, BIT2, BIT3, BIT4, BIT5. BIT6 | Control Input. See truth table and control voltage tables. |  |
| 8 | Vss | Voltage supply. |  |
| 13 | RFOUT | This port is DC coupled and matched to 50 Ohms. | $\longrightarrow O$ RFOUT |

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## Outline Drawing



Die Packaging Information ${ }^{[1]}$
NOTES:

1. ALL DIMENSIONS IN INCHES (MILLIMETERS)

| Standard | Alternate |
| :---: | :---: |
| GP-1 (Gel Pack) | [2] |

2. DIE THICKNESS IS 0.004
3. BACKSIDE METALLIZATION: GOLD
4. BACKSIDE METAL IS GROUND
5. BOND PADS METALLIZATION: GOLD
[1] Refer to the "Packaging Information" section for die
6. OVERALL DIE SIZE $\pm 0.002$
[2] For alternate packaging information contact Hittite Microwave Corporation.

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## Assembly Diagram



## Handling Precautions

Follow these precautions to avoid permanent damage.
Storage: All bare die are placed in either Waffle or Gel based ESD protective containers, and then sealed in an ESD protective bag for shipment. Once the sealed ESD protective bag has been opened, all die should be stored in a dry nitrogen environment.
Cleanliness: Handle the chips in a clean environment. DO NOT attempt to clean the chip using liquid cleaning systems.
Static Sensitivity: Follow ESD precautions to protect against > $\pm 250 \mathrm{~V}$ ESD strikes.
Transients: Suppress instrument and bias supply transients while bias is applied. Use shielded signal and bias cables to minimize inductive pick-up.

General Handling: Handle the chip along the edges with a vacuum collet or with a sharp pair of bent tweezers. The surface of the chip has fragile air bridges and should not be touched with vacuum collet, tweezers, or fingers.

## Mounting

The chip is back-metallized and can be die mounted with electrically conductive epoxy. The mounting surface should be clean and flat.
Epoxy Die Attach: Apply a minimum amount of epoxy to the mounting surface so that a thin epoxy fillet is observed around the perimeter of the chip once it is placed into position. Cure epoxy per the manufacturer's schedule.

## Wire Bonding

Ball or wedge bond with 0.025 mm ( 1 mil ) diameter pure gold wire. Thermosonic wirebonding with a nominal stage temperature of 150 deg. $C$ and a ball bonding force of 40 to 50 grams or wedge bonding force of 18 to 22 grams is recommended. Use the minimum level of ultrasonic energy to achieve reliable wirebonds. Wirebonds should be started on the chip and terminated on the package or substrate. All bonds should be as short as possible $<0.31 \mathrm{~mm}$ ( 12 mils).

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